

Schottky Barrier Rectifiers

PRODUCT SUMMARY

Reverse Voltage 35 to 60 Volts Forward current 10.0 Amperes

FEATURES

Plastic package has Underwriters Laboratory Flammability Classifications 94V-0

Metal silicon junction, majority carrier conduction

Low power loss, high efficiency

Guardring for overvoltage protection

For use in low voltage, high frequency inverters, free wheeling,

and polarity protection applications

High temperature soldering guaranteed:

250°C/10 seconds, 0.25" (6.35mm) from case







MECHANICAL DATA

Case: JEDEC TO-220AC, ITO-220AC & TO-263AB molded

plastic body

Terminals: Plated leads, solderable per MIL-STD-750,

Method 2026

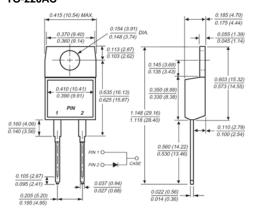
Polarity: As marked Mounting Position: Any

Mounting Torque: 10 in-lbs maximum Weight: 0.08 ounce, 2.24 grams

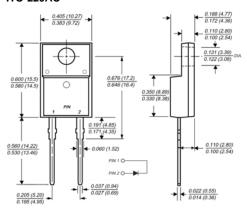


Pb-free; RoHS-compliant

TO-220AC

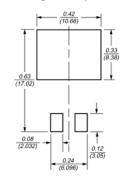


ITO-220AC

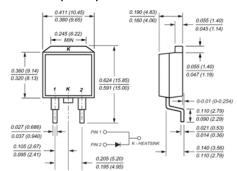




Mounting Pad Layout TO-263AB



TO-263AB(D2PAK)



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(T_C=25°C unless otherwise noted)

Parameter		Symbol	MBR1035	MBR1045	MBR1050	MBR1060	Unit
Maximum repetitive peak reverse voltage		V _{RRM}	35	45	50	60	Volts
Working peak reverse voltage		V _{RWM}	35	45	50	60	Volts
Maximum DC blocking voltage		V _{DC}	35	45	50	60	Volts
Maximum average forward rectified current (See Fig. 1)		I _{F(AV)}	10				Amps
Peak repetitive forward current (sq. wave, 20KHz) at T_c =135°C		I _{FRM}	20				Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		I _{FSM}	150				Amps
Peak repetitive reverse current at $t_p = 2.0 us$, 1KHz		I _{RRM}	1.0		0.5		Amps
Voltage rate of change (rated V _R)		dv/dt	10,000			V/us	
Maximum instantaneous forward voltage (Note 4)							
	at $\mbox{$\downarrow$}$ =10A, $\mbox{$T_{\rm c}$}$ =25°C at $\mbox{$\downarrow$}$ =20A, $\mbox{$T_{\rm c}$}$ =25°C at $\mbox{$\downarrow$}$ =20A, $\mbox{$T_{\rm c}$}$ =25°C		-		0.80		Volts
			0.57		0.70		
			0.84		0.95		
	at I ₌ =20A, T _c =125°C		0.	72 0.85		85	
Maximum instantaneous reverse current at rated DC blocking voltage (Note 4)	T _c =25°C	I _R	0.10				mA
	T _c =125°C		15				
Maximum thermal resistance from junction to case		R _{eJC}	MBR 2.0 / MBRF 4.0 / MBRB 2.0				°C/W
RMS Isolation voltage (MBRF type only) from terminals to heatsink with t = 1.0 second, RH \leq 30%		V _{ISOL}	4500 (Note 1) 3500 (Note 2) 1500 (Note 3)				Volts
Operating junction temperature range		T,	-55 to +150			°C	
Storage temperature range		T _{stg}	-55 to +150				°C

Notes

- 1. Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset
- 2. Clip mounting (on case), where leads do overlap heatsink
- 3. Screw mounting with 4-40 screw, where washer diameter is < 4.9 mm (0.19")
- 4. Pulse test: 300us pulse width, 1% duty cycle

100

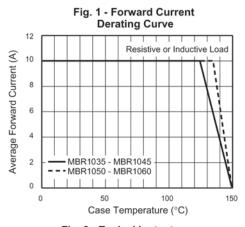
10

Number of Cycles at 60 Hz



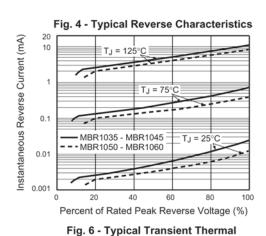
RATINGS AND CHARACTERISTIC CURVES

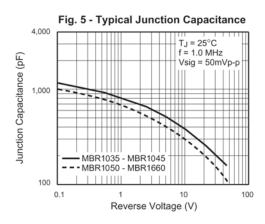
(T_A=25°C unless otherwise noted)

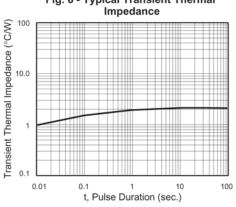


0.1

Fig. 3 - Typical Instantaneous Forward Characteristics Instantaneous Forward Current (A) T_J = 150°C 10 Pulse Width = 300µs = 25°C MBR1035 - MBR1045 MBR1050 - MBR1060 0.6 0 0.2 0.4 0.8 1.0 1.2 Instantaneous Forward Voltage (V)







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